

FIELD PROGRAMMABLE TRIPLE OUTPUT SS VERSACLOCK SYNTHESIZER **ICS343**

Description

The ICS343 is a low cost, triple-output, field programmable clock synthesizer. The ICS343 can generate three output frequencies from 250 kHz to 200 MHz, using up to three independently configurable PLLs. The outputs may employ Spread Spectrum techniques to reduce system electro-magnetic interference (EMI).

Using ICS' VersaClock™ software to configure the PLL and output, the ICS343 contains a One-Time Programmable (OTP) ROM to allow field programmability. Using Phase-Locked Loop (PLL) techniques, the device runs from a standard fundamental mode, inexpensive crystal, or clock. It can replace multiple crystals and oscillators, saving board space and cost.

The device also has a power down feature that tri-states the clock outputs and turns off the PLLs when the $\overline{\text{PDTS}}$ pin is taken low.

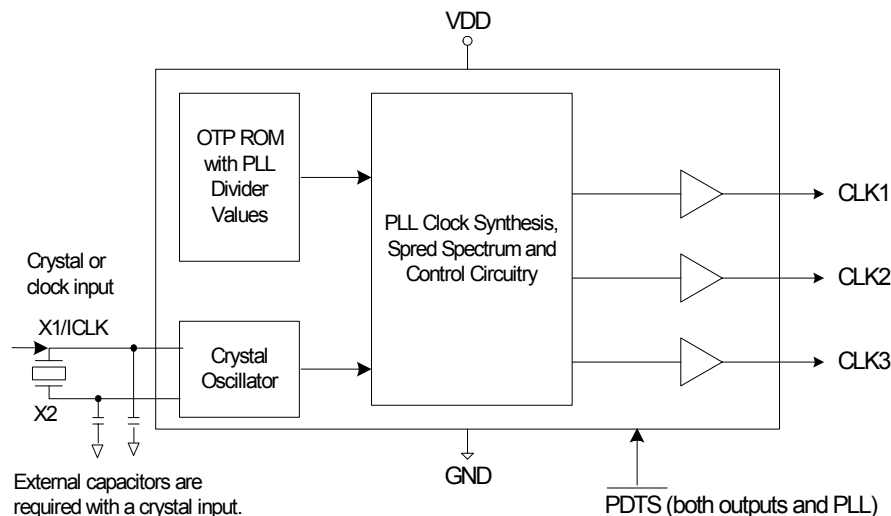
The ICS343 is also available in factory-programmed custom versions for high-volume applications.

Features

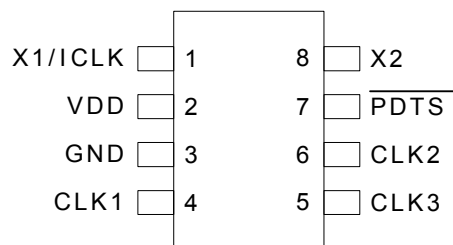
- 8-pin SOIC package
- Highly accurate frequency generation
 - M/N Multiplier PLL: $M = 1 \dots 2048$, $N = 1 \dots 1024$
- Output clock frequencies up to 200 MHz
- Spread spectrum capability for lower system EMI
 - Center or Down Spread up to 4% total
 - Selectable 32 kHz or 120 kHz modulation
- Input crystal frequency from 5 to 27 MHz
- Input clock frequency from 2 to 50 MHz
- Operating voltage of 3.3 V, using advanced, low power CMOS process
- For one output clock, use the ICS341. For two output clocks, see the ICS342. For more than three outputs, see the ICS345 or ICS348.
- Available in Pb (lead) free packaging

NOTE: EOL for non-green parts to occur on 5/13/10 per PDN U-09-01

Block Diagram



Pin Assignment



8-pin (150 mil) SOIC

Output Clock Selection Table

	CLK2	CLK2	CLK3
Output Frequency	User Configurable	User Configurable	User Configurable
Spread Amount	User Configurable	User Configurable	User Configurable

Pin Descriptions

Pin Number	Pin Name	Pin Type	Pin Description
1	X1/ICLK	XI	Connect this pin to a crystal or external clock input.
2	VDD	Power	Connect to +3.3 V.
3	GND	Power	Connect to ground.
4	CLK1	Output	Clock output. Weak internal pull-down when tri-state.
5	CLK3	Output	Clock output. Weak internal pull-down when tri-state.
6	CLK2	Output	Clock output. Weak internal pull-down when tri-state.
7	PDS	Input	Powers down entire chip. Tri-states CLK outputs when low. Internal pull-up.
8	X2	XO	Connect this pin to a crystal, or float for clock input.

External Components

Series Termination Resistor

Clock output traces over one inch should use series termination. To series terminate a 50Ω trace (a commonly used trace impedance), place a 33Ω resistor in series with the clock line, as close to the clock output pin as possible. The nominal impedance of the clock output is 20Ω.

Decoupling Capacitor

As with any high-performance mixed-signal IC, the ICS343 must be isolated from system power supply noise to perform optimally.

A decoupling capacitor of 0.01μF must be connected between VDD and the PCB ground plane.

Crystal Load Capacitors

The device crystal connections should include pads for small capacitors from X1 to ground and from X2 to ground. These capacitors are used to adjust the stray capacitance of the board to match the nominally required crystal load

capacitance. Because load capacitance can only be increased in this trimming process, it is important to keep stray capacitance to a minimum by using very short PCB traces (and no vias) between the crystal and device. Crystal capacitors must be connected from each of the pins X1 and X2 to ground.

The value (in pF) of these crystal caps should equal $(C_L - 6 \text{ pF}) \times 2$. In this equation, C_L = crystal load capacitance in pF. Example: For a crystal with a 16 pF load capacitance, each crystal capacitor would be 20 pF $[(16 - 6) \times 2] = 20$.

PCB Layout Recommendations

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

1) The 0.01μF decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between the decoupling capacitor and VDD pin. The PCB trace to VDD pin should

be kept as short as possible, as should the PCB trace to the ground via. Distance of the ferrite bead and bulk decoupling from the device is less critical.

2) The external crystal should be mounted just next to the device with short traces. The X1 and X2 traces should not be routed next to each other with minimum spaces, instead they should be separated and away from other traces.

3) To minimize EMI, the 33Ω series termination resistor (if needed) should be placed close to the clock output.

4) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers. Other signal traces should be routed away from the ICS343. This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

ICS343 Configuration Capabilities

The architecture of the ICS343 allows the user to easily configure the device to a wide range of output frequencies, for a given input reference frequency.

The frequency multiplier PLL provides a high degree of precision. The M/N values (the multiplier/divide values available to generate the target VCO frequency) can be set within the range of M = 1 to 2048 and N = 1 to 1024.

The ICS343 also provides separate output divide values, from 2 through 20, to allow the two output clock banks to support widely differing frequency values from the same PLL.

Each output frequency can be represented as:

$$\text{OutputFreq} = \frac{\text{REFFreq}}{\text{OutputDivide}} \cdot \frac{M}{N}$$

ICS VersaClock Software

ICS applies years of PLL optimization experience into a user-friendly software that accepts the user's target reference clock and output frequencies and generates the lowest jitter, lowest power configuration, with only a press of a button. The user does not need to have prior PLL experience or determine the optimal VCO frequency to support multiple output frequencies.

VersaClock software quickly evaluates accessible VCO frequencies with available output divide values and provides an easy to understand, bar code rating for the target output frequencies. The user may evaluate output accuracy, performance trade-off scenarios in seconds.

Spread Spectrum Modulation

The ICS343 utilizes frequency modulation (FM) to distribute energy over a range of frequencies. By modulating the output clock frequencies, the device effectively lowers energy across a broader range of frequencies; thus, lowering a system's electro-magnetic interference (EMI). The modulation rate is the time from transitioning from a minimum frequency to a maximum frequency and then back to the minimum.

Spread Spectrum Modulation can be applied as either "center spread" or "down spread". During center spread modulation, the deviation from the target frequency is equal in the positive and negative directions. The effective average frequency is equal to the target frequency. In applications where the clock is driving a component with a maximum frequency rating, down spread should be applied. In this case, the maximum frequency, including modulation, is the target frequency. The effective average frequency is less than the target frequency.

The ICS343 operates in both center spread and down spread modes. For center spread, the frequency can be modulated between +/- 0.125% to +/-2.0%. For down spread, the frequency can be modulated between -0.25% to -4.0%.

Both output frequency banks will utilize identical spread spectrum percentage deviations and modulation rates, if a common VCO frequency can be identified.

Spread Spectrum Modulation Rate

The spread spectrum modulation frequency applied to the output clock frequency may occur at a variety of rates. For applications requiring the driving of "down-circuit" PLLs, Zero Delay Buffers, or those adhering to PCI standards, the spread spectrum modulation rate should be set to 30-33 kHz. For other applications, a 120 kHz modulation option is available.

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the ICS343. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Parameter	Condition	Min.	Typ.	Max.	Units
Supply Voltage, VDD	Referenced to GND			7	V
Inputs	Referenced to GND	-0.5		VDD+ 0.5	V
Clock Outputs	Referenced to GND	-0.5		VDD+ 0.5	V
Storage Temperature		-65		150	°C
Soldering Temperature	Max 10 seconds			260	°C
Junction Temperature				125	°C

Recommended Operation Conditions

Parameter	Min.	Typ.	Max.	Units
Ambient Operating Temperature (ICS343M)	0		+70	°C
Ambient Operating Temperature (ICS343MI)	-40		+85	°C
Power Supply Voltage (measured in respect to GND)	+3.15	+3.3	+3.45	V
Power Supply Ramp Time			4	ms

DC Electrical Characteristics

Unless stated otherwise, **VDD = 3.3V ±5%**, Ambient Temperature -40 to +85°C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Operating Voltage	VDD		3.15	3.3	3.45	V
Operating Supply Current Input High Voltage	IDD	Configuration Dependent - See VersaClock™ Estimates				mA
		Three 33.3333 MHz outputs, PDTS = 1, No load Note 1		14		mA
		$\overline{\text{PDTS}} = 0$		20		μA
Input High Voltage, $\overline{\text{PDTS}}$	V _{IH}		VDD-0.5			V
Input Low Voltage, $\overline{\text{PDTS}}$	V _{IL}				0.4	V
Input High Voltage	V _{IH}	ICLK	VDD/2+1			V
Input Low Voltage	V _{IL}	ICLK			VDD/2-1	V
Output High Voltage (CMOS High)	V _{OH}	I _{OH} = -4 mA	VDD-0.4			V
Output High Voltage	V _{OH}	I _{OH} = -12 mA	2.4			V
Output Low Voltage	V _{OL}	I _{OL} = 12 mA			0.4	V
Short Circuit Current	I _{OS}			±70		mA
Nominal Output Impedance	Z _O			20		Ω
Internal Pull-up Resistor	R _{PUP}	$\overline{\text{PDTS}}$ pin		250		kΩ
Internal Pull-down Resistor	R _{PD}	CLK output		525		kΩ
Input Capacitance	C _{IN}	Inputs		4		pF

Note 1: Example with 25 MHz crystal input with three outputs of 33.3 MHz, no load, and VDD = 3.3 V.

AC Electrical Characteristics

Unless stated otherwise, $V_{DD} = 3.3V \pm 5\%$, Ambient Temperature -40 to $+85^{\circ}C$

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Input Frequency	F_{IN}	Fundamental Crystal	5		27	MHz
		Input Clock	2		50	MHz
Output Frequency			0.25		200	MHz
Output Rise Time	t_{OR}	20% to 80%, Note 1		1		ns
Output Fall Time	t_{OF}	80% to 20%, Note 1		1		ns
Duty Cycle		Note 2	40	49-51	60	%
Output Frequency Synthesis Error		Configuration Dependent	TBD			ppm
Power-up time		PLL lock time from power-up, Note 3		4	10	ms
		$\overline{PDT\overline{S}}$ goes high until stable CLK output, Spread Spectrum Off, Note 3		0.2	2	ms
		$\overline{PDT\overline{S}}$ goes high until stable CLK output, Spread Spectrum On, Note 3		4	7	ms
One Sigma Clock Period Jitter		Configuration Dependent		50		ps
Maximum Absolute Jitter	t_{ja}	Deviation from Mean. Configuration Dependent		± 200		ps

Note 1: Measured with 15 pF load.

Note 2: Duty Cycle is configuration dependent. Most configurations are minimum 45% and maximum 55%.

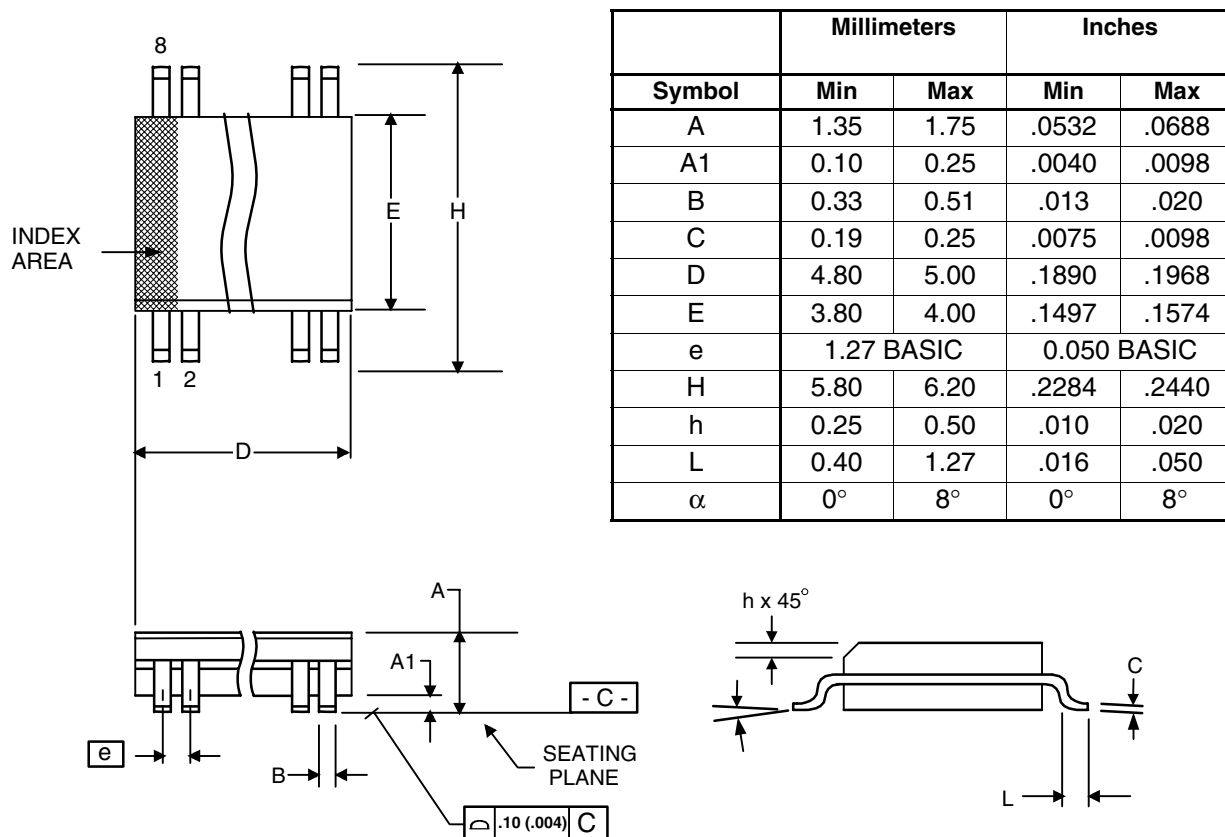
Note 3: ICS test mode output occurs for first 170 clock cycles on CLK3 for each PLL powered up.

Thermal Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Thermal Resistance Junction to Ambient	θ_{JA}	Still air		150		$^{\circ}C/W$
	θ_{JA}	1 m/s air flow		140		$^{\circ}C/W$
	θ_{JA}	3 m/s air flow		120		$^{\circ}C/W$
Thermal Resistance Junction to Case	θ_{JC}			40		$^{\circ}C/W$

Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Body)

Package dimensions are kept current with JEDEC Publication No. 95



Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
343MP*	343MP	Tubes	8-pin SOIC	0 to +70° C
343MIP*	343MIP	Tubes	8-pin SOIC	-40 to +85° C
343MPLF	343MPLF	Tubes	8-pin SOIC	0 to +70° C
343MIPLF	343MIPLF	Tubes	8-pin SOIC	-40 to +85° C
343M-XX*	343M-XX	Tubes	8-pin SOIC	0 to +70° C
343MI-XX*	343MI-XX	Tubes	8-pin SOIC	-40 to +85° C
343M-XXLF	343MXXLF	Tubes	8-pin SOIC	0 to +70° C
343MI-XXLF	343MIXXL	Tubes	8-pin SOIC	-40 to +85° C
343M-XXT*	343M-XX	Tape and Reel	8-pin SOIC	0 to +70° C
343MI-XXT*	343MI-XX	Tape and Reel	8-pin SOIC	-40 to +85° C
343M-XXLFT	343MXXLF	Tape and Reel	8-pin SOIC	0 to +70° C
343MI-XXLFT	343MIXXL	Tape and Reel	8-pin SOIC	-40 to +85° C

***NOTE:** EOL for non-green parts to occur on 5/13/10 per PDN U-09-01

Parts that are ordered with a “LF” suffix to the part number are the Pb-Free configuration and are RoHS compliant.

The 343M-XX, 343M-XXLF, 343MI-XX, and 343MI-XXLF are factory programmed versions of the 343MP, 343MPLF, 343MIP, and 343MIPLF. A unique “-XX” suffix is assigned by the factory for each custom configuration, and a separate data sheet is kept on file. For more information on custom part numbers programmed at the factory, please contact your local IDT sales and marketing representative.

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